



DMT3009UFVW

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
	11mΩ @ V _{GS} = 10V	30A
30V	$13m\Omega @ V_{GS} = 4.5V$	25A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

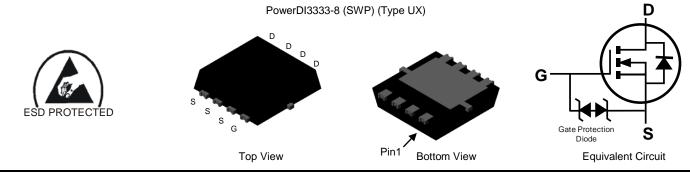
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Ultra Low Gate Threshold Voltage
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- ESD Protected Gate
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208(€3)
- Weight: 0.03 grams (Approximate)



Ordering Information (Note 4)

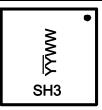
Part Number	Case	Packaging
DMT3009UFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMT3009UFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



<u>SH</u>3 = Product Type Marking Code <u>YY</u>WW = Date Code Marking YY = Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	30	V	
Gate-Source Voltage		Vgss	±12	V
	T _A = +25°C T _A = +70°C	ID	10.6 8.5	Δ
Continuous Drain Current $V_{GS} = 10V$ (Note 7)	Tc = +25°C T _C = +70°C	lо	30 25	А
Maximum Continuous Body Diode Forward Current (Note 7)	·	ls	2.1	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	80	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1	Ism	80	А	
Avalanche Current, L = 0.1mH (Note 8)		las	19	А
Avalanche Energy, L = 0.1mH (Note 8)		E _{AS}	18	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	105.2	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	2.6	W
Thermal Resistance, Junction to Case (Note 6)	Steady State	RθJA	48.2	°C/W
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _θ JC	3.5	°C/W
Operating and Storage Temperature Range	•	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	· ·						
Drain-Source Breakdown Voltage	BVDSS	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	0.5		1.8	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descent		8.6	11		$V_{GS} = 10V, I_D = 11A$	
Static Drain-Source On-Resistance	Rds(on)	_	11.5	13	mΩ	V _{GS} = 4.5V, I _D = 7A	
Diode Forward Voltage	V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 8.8A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	894		pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss		381	—	pF		
Reverse Transfer Capacitance	Crss	_	76	—	pF		
Gate Resistance	Rg		1.1	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	-	14.6	—		V _{DS} = 15V, I _D = 10A	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	7.4	_	nC		
Gate-Source Charge	Qgs	_	1.6	_	nc		
Gate-Drain Charge	Q _{gd}	—	3.4	_			
Turn-On Delay Time	t _{D(ON)}	_	3.4	_		$V_{GS} = 10V, V_{DD} = 15V, R_g = 1\Omega,$ $I_D = 8.8A$	
Turn-On Rise Time	tR	_	5.5	_			
Turn-Off Delay Time	tD(OFF)	_	9.6	_	ns		
Turn-Off Fall Time	tF		1.6		1		
Body Diode Reverse Recovery Time	trr		17		ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	6.7	_	nC	IF = 10A, dl/dt = 100A/μs	

Notes:

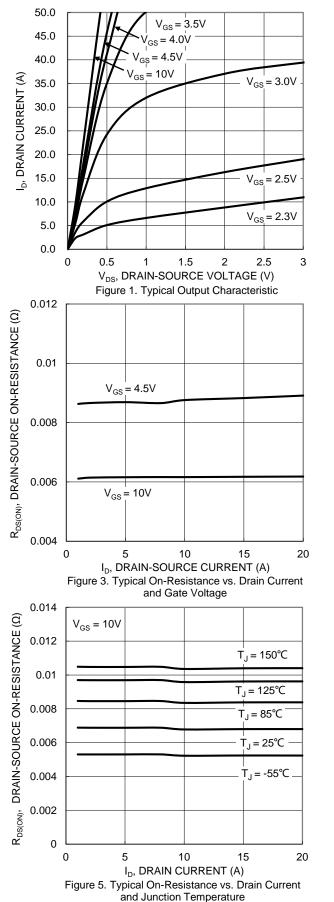
Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

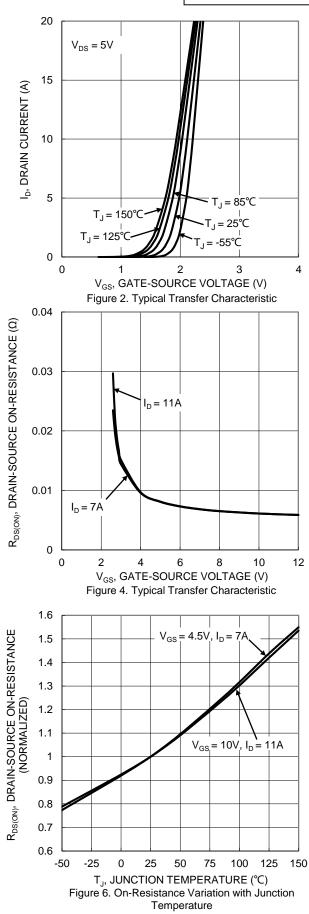
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



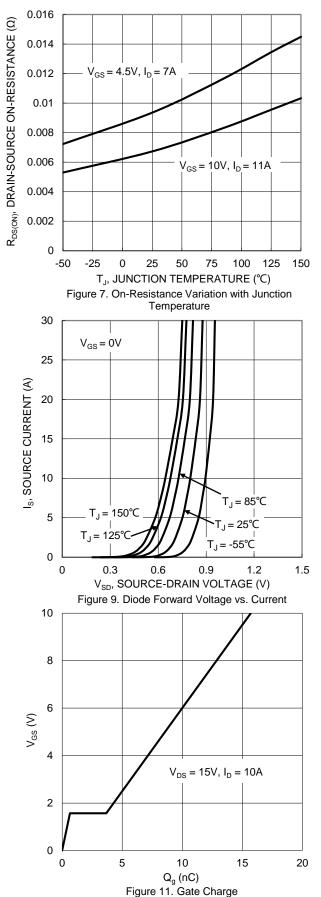


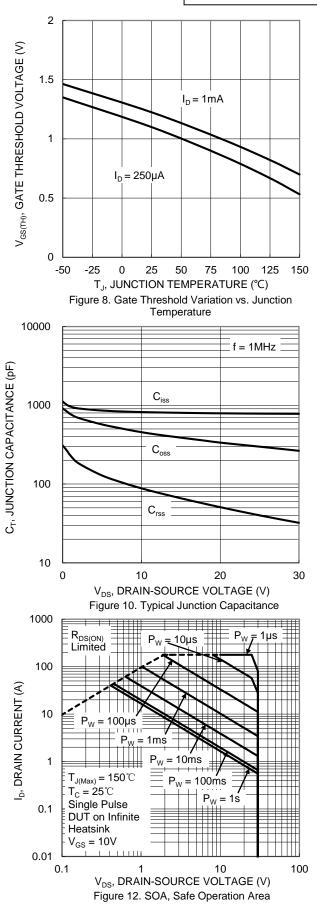












DMT3009UFVW Document number: DS41778 Rev. 3 - 2



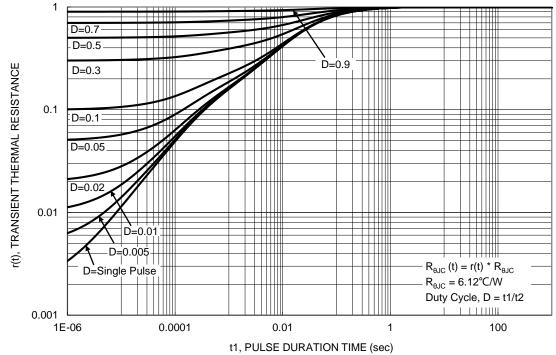


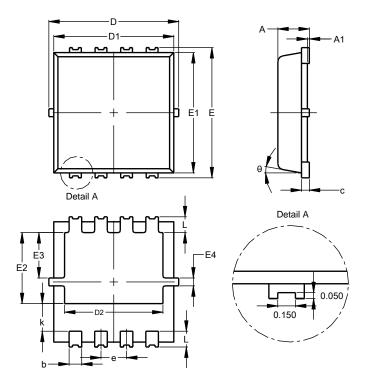
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

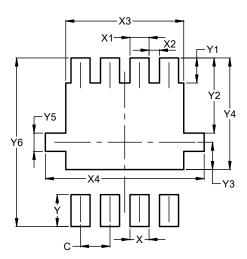


PowerDI3333-8 (SWP) (Type UX)				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05		
b	0.25	0.40	0.32	
C	0.10	0.25	0.15	
D	3.20	3.40	3.30	
D1	2.95	3.15	3.05	
D2	2.30	2.70	2.50	
E	3.20	3.40	3.30	
E1	2.95	3.15	3.05	
E2	1.60	2.00	1.80	
E3	0.95	1.35	1.15	
E4	0.10	0.30	0.20	
е	-	_	0.65	
k	0.50	0.90	0.70	
L	0.30	0.50	0.40	
θ	0°	12°	10°	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.600			
X4	3.500			
Y	0.700			
Y1	0.550			
Y2	1.650			
Y3	0.600			
Y4	2.450			
Y5	0.400			
Y6	3.700			



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